

PEMD14

50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k Ω , R2 = open

27 April 2023

Product data sheet

1. General description

NPN/PNP Resistor-Equipped Transistor (RET) in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PEMB14 NPN/NPN complement: PEMH14

2. Features and benefits

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place cost

3. Applications

- Low current peripheral driver
- Control of IC inputs
- · Replacement of general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base	[1]	-	-	50	V
Io	output current		[1]	-	-	100	mA
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ

- [1] For the PNP transistor with negative polarity.
- [2] See section "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		R1 R
4	GND2	GND (emitter) TR2	1	TR1
5	12	input (base) TR2		R1
6	O1	output (collector) TR1	1 2 3 SOT666	GND1 I1 O2 006aaa269

6. Ordering information

Table 3. Ordering information

Type number	Package	Package			
	Name	Description	Version		
PEMD14	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PEMD14	5B

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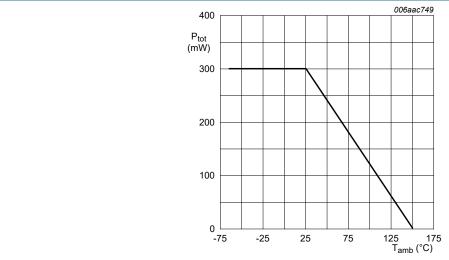
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		,	'		
V _{CBO}	collector-base voltage	open emitter	[1]	-	50	V
V_{CEO}	collector-emitter voltage	open base	[1]	-	50	V
V_{EBO}	emitter-base voltage	open collector	[1]	-	5	V
VI	input voltage	TR1 (NPN)		-5	40	V
		TR2 (PNP)		-40	5	V
Io	output current		[1]	-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2] [3]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2] [3]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] For the PNP transistor with negative polarity.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Reflow soldering is the only recommended soldering method.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	,						•
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	416	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.

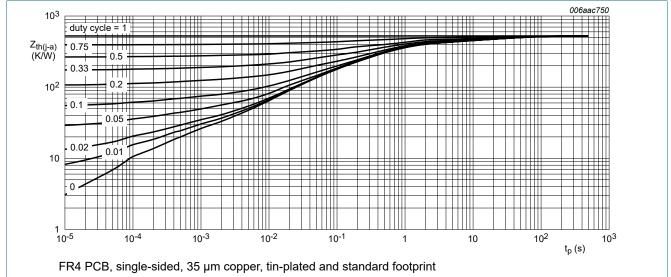


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

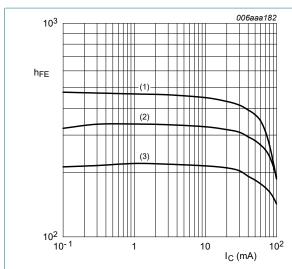
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	[1]	50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	[1]	50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C	[1]	-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C	[1]	-	-	1	μΑ
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C	[1]	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	[1]	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 1 mA; T _{amb} = 25 °C	[1]	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 0.1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	[1]	-	0.6	0.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 10 mA	[1]	4	2.5	-	V
R1	bias resistor 1 (input)		[2]	33	47	61	kΩ
Transistor 1	TR1 (NPN)					·	
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[3]	-	230	-	MHz
Transistor T	TR2 (PNP)		•		•		
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[3]	-	180	-	MHz

For the PNP transistor with negative polarity.
See section "Test information" for resistor calculation and test conditions. [2] [3]

Characteristics of built-in transistor

50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k Ω , R2 = open



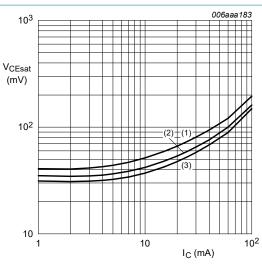
$$V_{CE} = 5 V$$

$$(1) T_{amb} = 100 ° ($$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -40 °C

TR1 (NPN): DC current gain as a function of Fig. 3. collector current; typical values

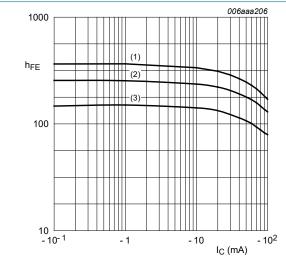


$$I_{\rm C}/I_{\rm B} = 20$$

$$I_{C}/I_{B} = 20$$
(1) $T_{amb} = 100 \, ^{\circ}C$
(2) $T_{amb} = 25 \, ^{\circ}C$
(3) $T_{amb} = -40 \, ^{\circ}C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



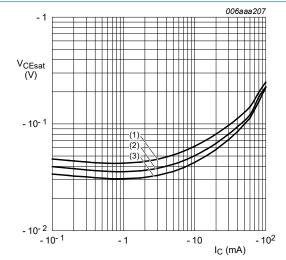
$$V_{CE}$$
 = -5 V

$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

TR2 (PNP): DC current gain as a function of Fig. 5. collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k Ω , R2 = open

11. Test information

Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_I = \frac{V(I_2) - V(I_I)}{I_2 - I_I}$$

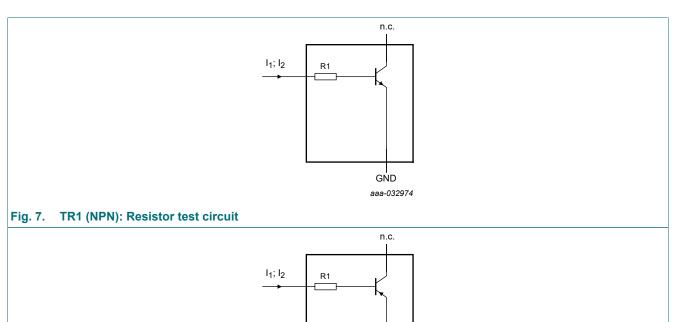


Fig. 8. TR2 (PNP): Resistor test circuit

Resistor test conditions

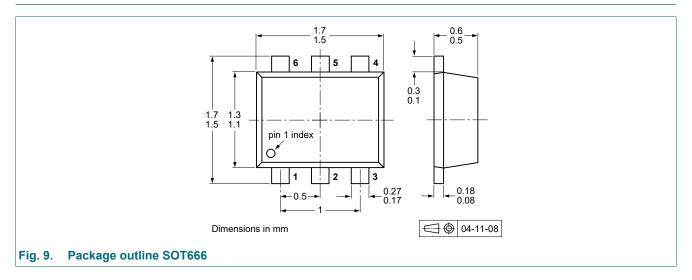
Table 8. Resistor test conditions

PEMD14	R1 (kΩ)	R2 (open)	Test conditions		
			I ₁	l ₂	
TR1 (NPN)	47	-	60 μA	110 μΑ	
TR2 (PNP)	47	-	-60 µA	-110 μA	

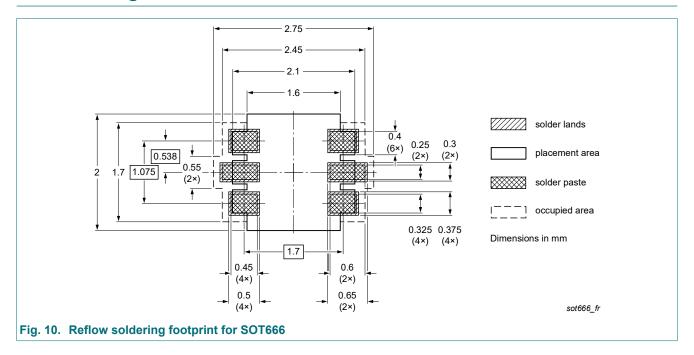
aaa-032975

50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k Ω , R2 = open

12. Package outline



13. Soldering



50 V, 100 mA NPN/PNP resistor-equipped transistor; R1 = 47 k Ω , R2 = open

14. Revision history

Table 9. Revision history

Tuble 9. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PEMD14 v.3	20230427	Product data sheet	-	PEMD14_PUMD14_2	
Modifications:	Nexperia. Legal texts have bee Family data sheet sp Section "Packing info	ita sheet has been redesion adapted to the new constituted to single type data cormation" removed. non-automotive qualificat	mpany name where appr sheets.		
PEMD14_PUMD14_2	20090902	Product data sheet	-	PEMD14_PUMD14_1	
PEMD14_PUMD14_1	20050114	Product data sheet	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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